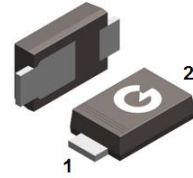


Features

- Fast switching speed
- High reverse breakdown voltage
- Low leakage current
- Halogen free
- Qualified to AEC-Q101 standards for high reliability

HF

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SOD-323T

Mechanical Data

- Case: SOD-323T
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TBAV3004HE	SOD-323T	4000 pcs / Tape & Reel	4P

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Repetitive Peak Reverse Voltage	V _{RRM}	350	V
Working Peak Reverse Voltage	V _{RWM}	300	V
DC Blocking Voltage	V _R	300	V
RMS Reverse Voltage	V _{R(RMS)}	212	V
Forward Continuous Current	I _F	225	mA
Repetitive Peak Forward Current	I _{FRM}	625	mA
Peak Forward Surge Current, t = 1μs	I _{FSM}	4	A
Non-Repetitive Peak Forward Surge Current, t = 1s	I _{FSM}	1	A

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	500	mW
Thermal Resistance Junction-to-Air ^{*1}	R _{θJA}	200	°C/W
Thermal Resistance Junction-to-Case ^{*1}	R _{θJC}	120	°C/W
Operating Junction Temperature Range	T _J	-65 ~ +150	°C
Storage Temperature Range	T _{STG}	-65 ~ +150	°C

Note 1: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	$I_R = 150\mu\text{A}$	350	-	-	V
Forward Voltage	V_F	$I_F = 20\text{mA}$	-	0.78	0.87	V
		$I_F = 100\text{mA}$	-	0.93	1.00	V
		$I_F = 200\text{mA}$	-	1.03	1.25	V
Maximum Peak Reverse Current	I_R	$V_R = 240\text{V}, T_J = 25^\circ\text{C}$	-	10	100	nA
		$V_R = 240\text{V}, T_J = 150^\circ\text{C}$	-	1	100	μA
Total Capacitance	C_J	$V_R = 0\text{V}, f = 1.0\text{MHz}$	-	2.8	5	pF
Reverse Recovery Time	t_{rr}	$I_F = I_R = 30\text{mA}$ $I_{rr} = 0.1 \times I_R, R_L = 100\Omega$	-	-	50	ns

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

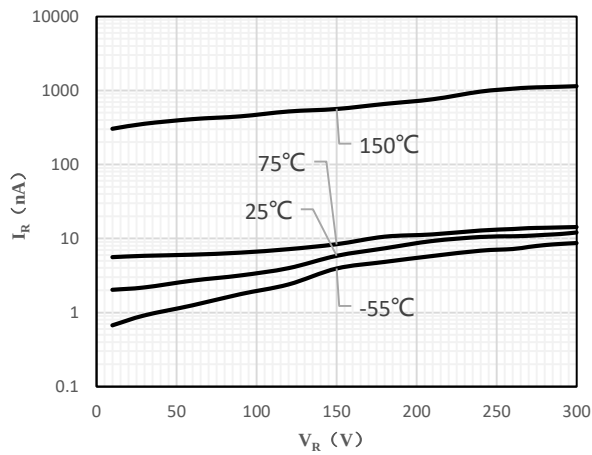


Fig 1 Typical Reverse Characteristic

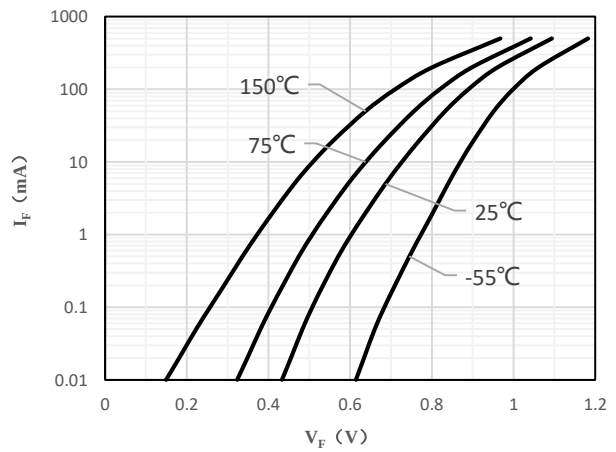


Fig 2 Typical Forward Characteristics

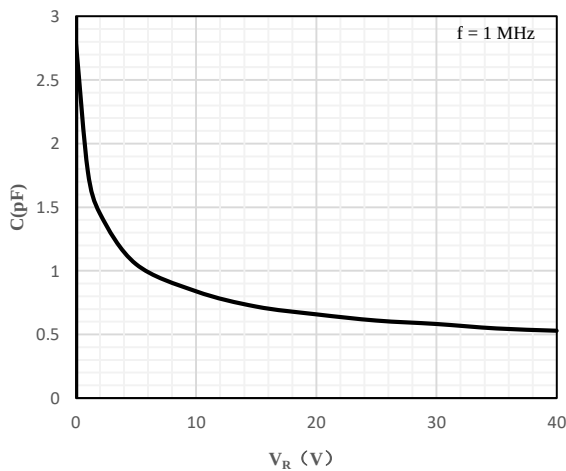


Fig 3 Capacitance vs. Reverse Voltage

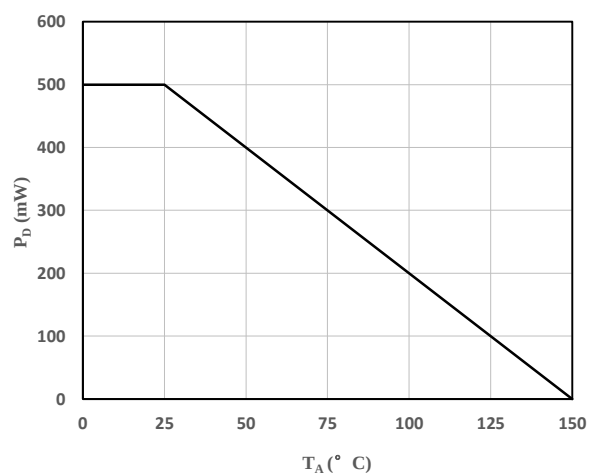
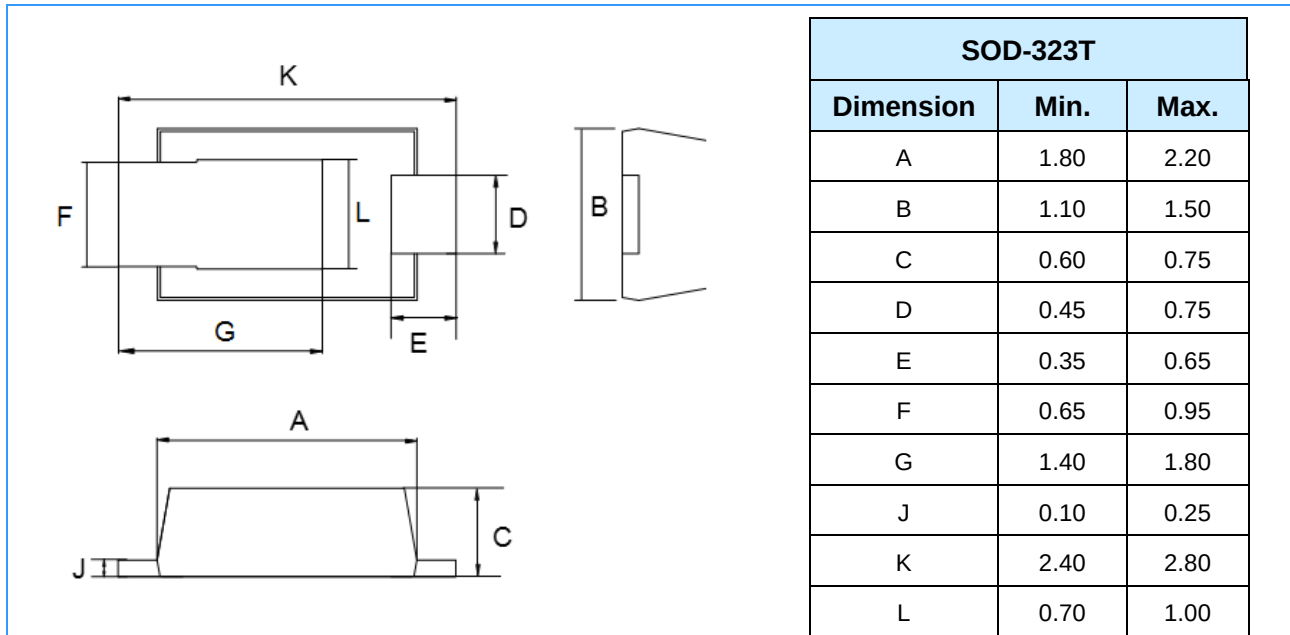
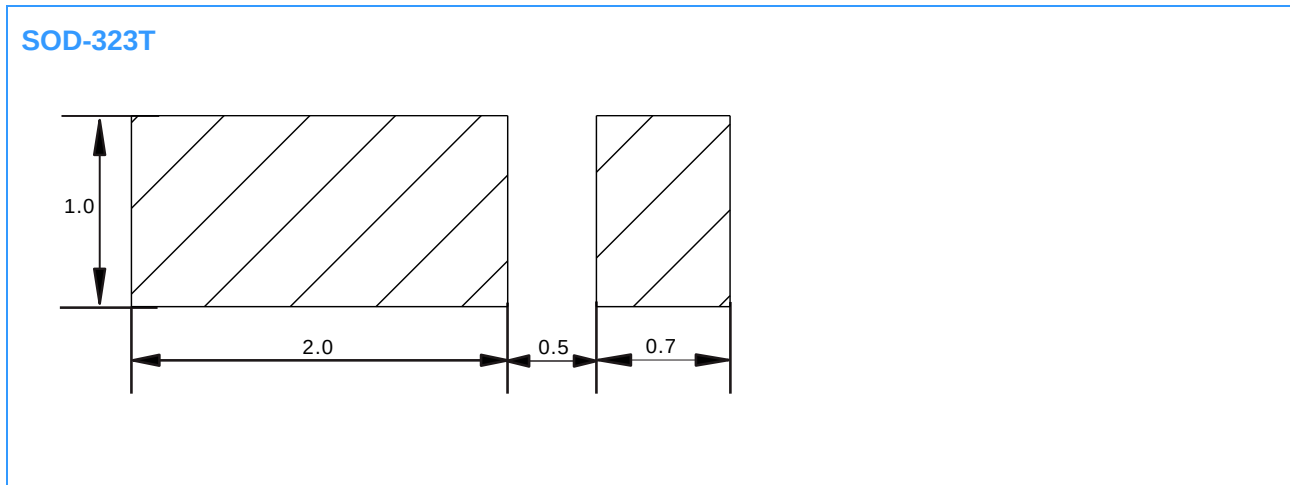


Fig 4 Power Derating Curve

Package Outline Dimensions (Unit: mm)



Mounting Pad Layout (Unit: mm)



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